

规格书编号

SPEC NO:

产品规格书 SPECIFICATION

CUSTOMER 客 户:					
PRODUCT 产品:	SAW FILTER				
MODEL NO 型 号:	HDF426AN F11				
PREPARED 编 制:	CHECKED 审 核	:			
APPROVED 批准:	DATE	2006-5-11			
客户确认 CUSTOMER RE	ECEIVED:				
审核 CHECKED	批准 APPROVED	日期 DATE			

无锡市好达电子股份有限公司 Shoulder Electronics Limited



更改历史记录 History Record

更改日期 Date	规格书编号 Spec. No.	产品型号 Part No.	客户产品型号 Customer No.	更改内容描述 Modify Content	备注 Remark



1. SCOPE

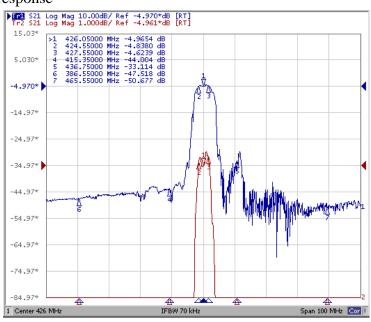
This specification shall cover the characteristics of SAW filter With F426AN used for the page system.

2. ELECTRICAL SPECIFICATION

DC Voltage VDC	10V
AC Voltage Vpp	10V50Hz/60Hz
Operation temperature	-40°C to +85°C
Storage temperature	-45°C to +85°C
RF Power Dissipation	0dBm

Electronic Characteristics

2-1. Typical frequency response

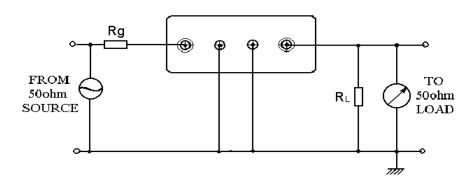


2-2. Electrical characteristics

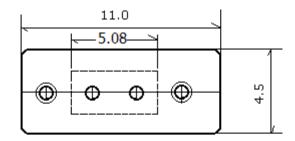
PART NUMBER	HDF426AN	UNIT
NOMINAL CENTERREQUENCY(Fo)	426.05	MHz
INSERTION LOSS: 1. Fo-100MHz TO Fo –39.5MHz 2. Fo-39.5MHz TO Fo-10.7MHz 3. Fo±1.5 MHz 4. Fo+10.7MHz TO Fo+39.5MHz 5. Fo+39.5 TO +100MHz	45.0Min 40.0 Min 6.0 Max 40.0Min 45.0 Min	dB
RIPPLE (WITH PASSBAND)	2.0 Max	dB
1dB BW	4.0 Type	MHz
INPUT AND OUTPUT IMPEDANCE	50/0	Ω/pF

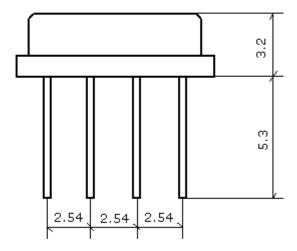
3.TEST CIRCUIT

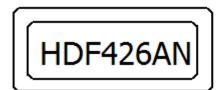
SAW FILTER



4. DIMENSION









SAW FILTER

5. ENVIRONMENTAL CHARACTERISTICS

5-1 High temperature exposure

Subject the device to $+85^{\circ}$ C for 16 hours. Then release the filter into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 2-2.

5-2 Low temperature exposure

Subject the device to -40° C for 16 hours. Then release the device into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 2-2.

5-3 Temperature cycling

Subject the device to a low temperature of -40° C for 30 minutes. Following by a high temperature of $+85^{\circ}$ C for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in 2-2.

5-4 Resistance to solder heat

Dip the device terminals no closer than 1.5mm into the solder bath at 260° C $\pm 10^{\circ}$ C for 10 ± 1 sec. Then release the device into the room conditions for 4 hours. The device shall meet the specifications in 2-2.

5-5 Solderability

Subject the device terminals into the solder bath at 245° C $\pm 5^{\circ}$ C for 5s, More than 95% area of the terminals must be covered with new solder. It shall meet the specifications in 2-2.

5-6 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in 2-2.

5-7 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in 2-2.

6. REMARK

6.1 Static voltage

Static voltage between signal load & ground may cause deterioration &destruction of the component. Please avoid static voltage.

6.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

6.3 Soldering

Only leads of component may be soldered. Please avoid soldering another part of component.